

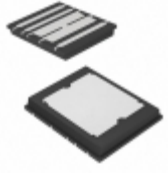
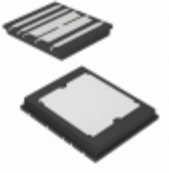
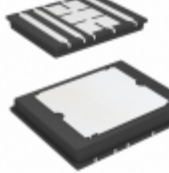
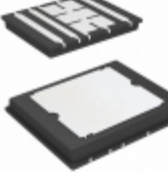
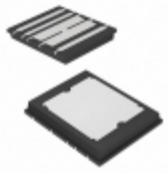
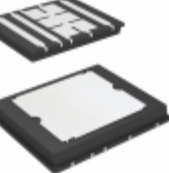
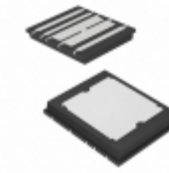
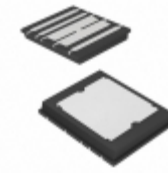
	<h2>SIE802DF-T1-E3</h2>
	<p>Hersteller-Teilenummer: SIE802DF-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 60A 10-POLARPAK</p> <p>Datenblätter:  SIE802DF-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 793 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIE802DF-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 60A 10-POLARPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	793 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	10-PolarPAK® (L)
Supplier Device-Gehäuse	10-PolarPAK® (L)
Verlustleistung (max)	5.2W (Ta), 125W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	60A (Tc)
Rds On (Max) @ Id, Vgs	1.9 mOhm @ 23.6A, 10V
VGS (th) (Max) @ Id	2.7V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	160nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	7000pF @ 15V
Verpackung	Tape & Reel (TR)



















































SIE802DF-T1-E3 ist neu im Original, Suche SIE802DF-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIE802DF-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIE802DF-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIE800DF-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 50A 10-POLARPAK</p>	 <p>SIE800DF-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 50A 10-POLARPAK</p>	 <p>SIE802DF-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 60A 10-POLARPAK</p>	 <p>SIE802DF-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 60A POLARPAK</p>
 <p>SIE804DF-T1-GE3 Vishay / Siliconix MOSFET N-CH 150V 37A POLARPAK</p>	 <p>SIE726DF-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 60A POLARPAK</p>	 <p>SIE804DF-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 150V 37A POLARPAK</p>	 <p>SIE800DF-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 50A POLARPAK</p>

heiße Teile

Mehr

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 ESDA5V35C5	 EXQ125-48S1V2J	 F2405D-2W	 FAN2518S25X	 FBMJ3216HS480NT
 FJX4013RTF	 ICS9LVS3197AKLFT	 IP-210-CU	 IRKD71-12	 LTC1484CMS8#TRPBF
 MAX6719UTSVD3+T	 N0339WC160	 NJM78L15UA	 P3596-3.3V	 SIE01-03
 SIE01-06	 SIE20031	 SIE20034	 SIE501.8LT	 SIE503.3LT
 SIE503.3LTR	 SIE800DF-T1-E3	 SIE800DF-T1-E3	 SIE802DF-T1-E3	 SIE808DF-T1-E3
 SIE808DF-T1-E3	 SIE812DF	 SIE848DF-T1-E3	 SIE848DF-T1-E3	 SIE862DF-T1-GE3
 SIE862DF-T1-GE3	 SIE864DP-T1-GE3	 SIE874DF-T1-GE3	 SIE874DF-T1-GE3	 SKT2400/16E
 SN65C3221PWR	 SST39VF800A-90-4C-EK	 STB55NF03LT4	 STK795-521C	 T9GH1809I2DH
 TC1185-3.0VCT	 V300B3V3T150AL	 VRE1205S-1W	 VSKL300-08PBF	 XC6120C152HR-G

Contact us: Info@Y-IC.com

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